- Function and Pinout Compatible With the Fastest Bipolar Logic
- 25-Ω Output Series Resistors Reduce Transmission-Line Reflection Noise
- Reduced V_{OH} (Typically = 3.3 V) Version of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- 3-State Outputs
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- Fully Compatible With TTL Input and Output Logic Levels
- 12-mA Output Sink Current
 15-mA Output Source Current

Q OR SO PACKAGE (TOP VIEW) OE [20 VCC O₀ [] 2 19 O₇ D₀ [] 3 18 D₇ $D_1 \prod 4$ 17 D₆ O₁ [] 5 16 O₆ 15 \ O₅ $D_2 \begin{bmatrix} 1 \end{bmatrix} 7$ 14 D₅ $D_3 [8]$ 13 D₄ O₃ **[**] 9 12 O₄ GND [] 10 11 **∏** LE

description

The CY74FCT2373T is an 8-bit, high-speed CMOS, TTL-compatible buffered latch with 3-state outputs that is ideal for driving high-capacitance loads, such as memory and address buffers. On-chip 25- Ω termination resistors at the outputs reduce system noise caused by reflections. The CY74FCT2373T can replace the CY74FCT373T to reduce noise in an existing design.

When the latch-enable (LE) input is high, the flip-flops appear transparent to the data. Data that meets the required setup times are latched when LE transitions from high to low. Data appears on the bus when the output-enable (\overline{OE}) input is low. When \overline{OE} is high, the bus output is in the high-impedance state. In this mode, data can be entered into the latches.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

TA	PACKAGE†		ļ		SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP – Q	Tape and reel	4.7	CY74FCT2373CTQCT	FCT2373C		
	SOIC - SO	Tube	4.7	CY74FCT2373CTSOC	FCT2373C		
–40°C to 85°C		Tape and reel	4.7	CY74FCT2373CTSOCT	FC12373C		
	QSOP – Q	Tape and reel	5.2	CY74FCT2373ATQCT	FCT2373A		
	QSOP – Q	Tape and reel	8	CY74FCT2373TQCT	FCT2373		

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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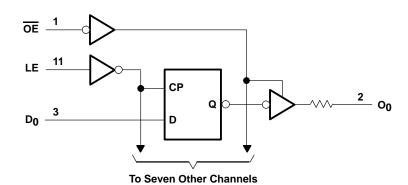


FUNCTION TABLE

	INPUTS		OUTPUT
OE	LE	D	0
L	Н	Н	Н
L	Н	L	L
L	L	Χ	Q ₀
Н	X	Χ	Z

H = High logic level, L = Low logic level, X = Don't care, Z = High-impedance state, Q_0 = Previous state of flip flops (Q_{0-1})

logic diagram



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential	0.5 V to 7 V
DC input voltage range	\dots -0.5 V to 7 V
DC output voltage range	\dots -0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ _{JA} (see Note 1): Q package	68°C/W
SO package	58°C/W
Ambient temperature range with power applied, T _A	. −65°C to 135°C
Storage temperature range, T _{stg}	. -65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.75	5	5.25	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
ЮН	High-level output current			-15	mA
loL	Low-level output current			12	mA
TA	Operating free-air temperature	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	s	MIN	TYP†	MAX	UNIT
VIK	$V_{CC} = 4.75 V$,	$I_{IN} = -18 \text{ mA}$			-0.7	-1.2	V
VOH	$V_{CC} = 4.75 \text{ V},$	I _{OH} = -15 mA		2.4	3.3		V
V _{OL}	$V_{CC} = 4.75 \text{ V},$	I _{OL} = 12 mA			0.3	0.55	V
ROUT	$V_{CC} = 4.75 \text{ V},$	$I_{OL} = 12 \text{ mA}$		20	28	40	Ω
V _{hys}	All inputs				0.2		V
lį	V _{CC} = 5.25 V,	VIN = VCC				5	μΑ
lн	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 2.7 \text{ V}$				±1	μΑ
I _{IL}	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 0.5 V$				±1	μΑ
lozh	$V_{CC} = 5.25 \text{ V},$	V _{OUT} = 2.7 V				10	μΑ
lozL	$V_{CC} = 5.25 \text{ V},$	V _{OUT} = 0.5 V				-10	μΑ
los [‡]	$V_{CC} = 5.25 \text{ V},$	VOUT = 0 V		-60	-120	-225	mA
l _{off}	$V_{CC} = 0 V$,	V _{OUT} = 4.5 V				±1	μΑ
Icc	$V_{CC} = 5.25 \text{ V},$	$V_{IN} \le 0.2 V$,	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2	mA
ΔlCC	V _{CC} = 5.25 V, V _{IN}	= 3.4 V\$, f ₁ = 0, Outputs op	oen		0.5	2	mA
I _{CCD} ¶		input switching at 50% duty 0.2 V or $V_{\text{IN}} \ge V_{\text{CC}} - 0.2 \text{ V}$	y cycle, Outputs open,		0.06	0.12	mA/ MHz
	V _{CC} = 5.25 V,	One input switching at f ₁ = 10 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4	
1-#	Outputs open,	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1	2.4	mA
iC"	$I_{C}^{\#}$ $OE = GND,$ $LE = V_{CC}$	Eight bits switching at f ₁ = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1.3	2.6	IIIA
		at 50% duty cycle	V _{IN} = 3.4 V or GND		3.3	10.6	
C _i					6	10	pF
Co					8	12	pF

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

= Total supply current lC.

ICC = Power-supply current with CMOS input levels

 ΔI_{CC} = Power-supply current for a TTL high input ($V_{IN} = 3.4 \text{ V}$)

 D_H = Duty cycle for TTL inputs high = Number of TTL inputs at DH

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

= Clock frequency for registered devices, otherwise zero

= Input signal frequency

= Number of inputs changing at f₁

All currents are in milliamperes and all frequencies are in megahertz.

|| Values for these conditions are examples of the I_{CC} formula.



[‡] Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

 $[\]$ Per TTL-driven input ($V_{IN} = 3.4 \text{ V}$); all other inputs at V_{CC} or GND

This parameter is derived for use in total power-supply calculations.

[#]IC $= I_{CC} + \Delta I_{CC} \times D_H \times N_T + I_{CCD}(f_0/2 + f_1 \times N_1)$ Where:

CY74FCT2373T 8-BIT LATCH WITH 3-STATE OUTPUTS

SCCS039B - SEPTEMBER 1994 - REVISED OCTOBER 2001

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

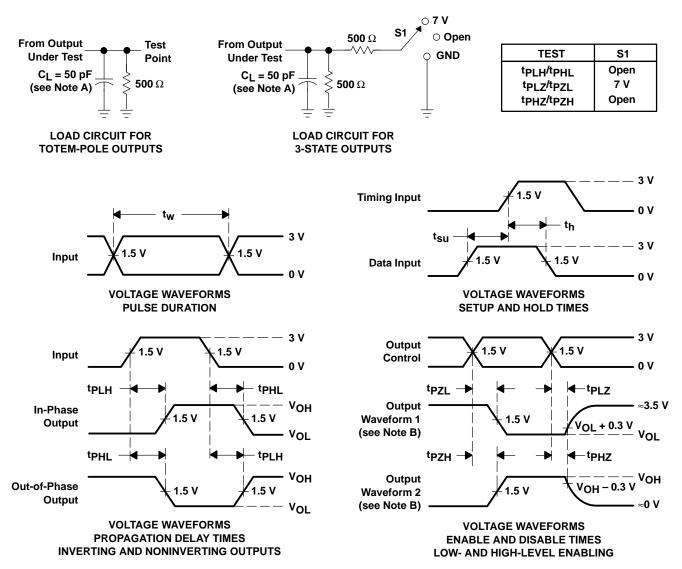
				CY74FCT2373T		CY74FCT2373AT		CY74FCT2373CT	
			MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _W	Pulse duration, LE high		6		5		5		ns
t _{su}	Setup time, D to LE	High to low	2		2		2		ns
t _h	Hold time, D to LE	High to low	1.5		1.5		1.5		ns

switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	CY74FC	Г2373Т	CY74FCT	2373AT	CY74FCT	2373CT	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	D	0	1.5	8	1.5	5.2	1.5	4.7	ns
t _{PHL}			1.5	8	1.5	5.2	1.5	4.7	115
^t PLH	LE	0	2	13	2	8.5	2	5.5	ns
t _{PHL}	LE		2	13	2	8.5	2	5.5	115
^t PZH	<u> </u>	0	1.5	11	1.5	6.5	1.5	5.5	ns
t _{PZL}	ŌĒ	0	1.5	11	1.5	6.5	1.5	5.5	116
^t PHZ	ŌĒ	0	1.5	7	1.5	5.5	1.5	5	ns
tPLZ	OE .		1.5	7	1.5	5.5	1.5	5	115



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(5)	(4)	(5)		(0)
CY74FCT2373CTSOC	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2373C
CY74FCT2373CTSOC.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2373C
CY74FCT2573ATQCT	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2573A
CY74FCT2573ATQCT.B	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2573A
CY74FCT2573CTQCT	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2573C
CY74FCT2573CTQCT.B	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2573C
CY74FCT2573CTSOC	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2573C
CY74FCT2573CTSOC.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2573C
CY74FCT2573CTSOCT	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2573C
CY74FCT2573CTSOCT.B	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2573C
CY74FCT2573TSOC	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2573
CY74FCT2573TSOC.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2573
CY74FCT2573TSOCT	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2573
CY74FCT2573TSOCT.B	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT2573

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT2573ATQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2573CTQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2573CTSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CY74FCT2573TSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1



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*All dimensions are nominal

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Device	Package Type Package Drawing Pins		SPQ	Length (mm)	Width (mm)	Height (mm)	
CY74FCT2573ATQCT	SSOP	DBQ	20	2500	353.0	353.0	32.0
CY74FCT2573CTQCT	SSOP	DBQ	20	2500	353.0	353.0	32.0
CY74FCT2573CTSOCT	SOIC	DW	20	2000	356.0	356.0	45.0
CY74FCT2573TSOCT	SOIC	DW	20	2000	356.0	356.0	45.0

PACKAGE MATERIALS INFORMATION

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TUBE

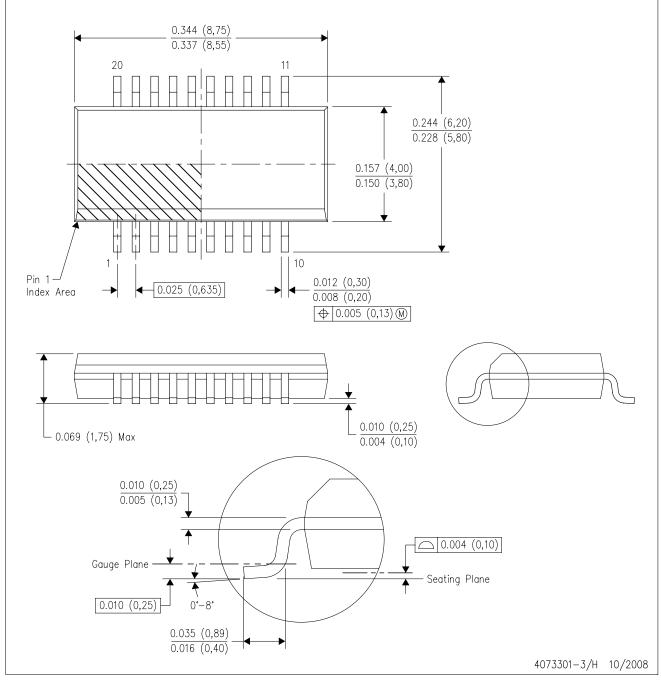


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CY74FCT2373CTSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT2373CTSOC.B	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT2573CTSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT2573CTSOC.B	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT2573TSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT2573TSOC.B	DW	SOIC	20	25	507	12.83	5080	6.6

DBQ (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AD.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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